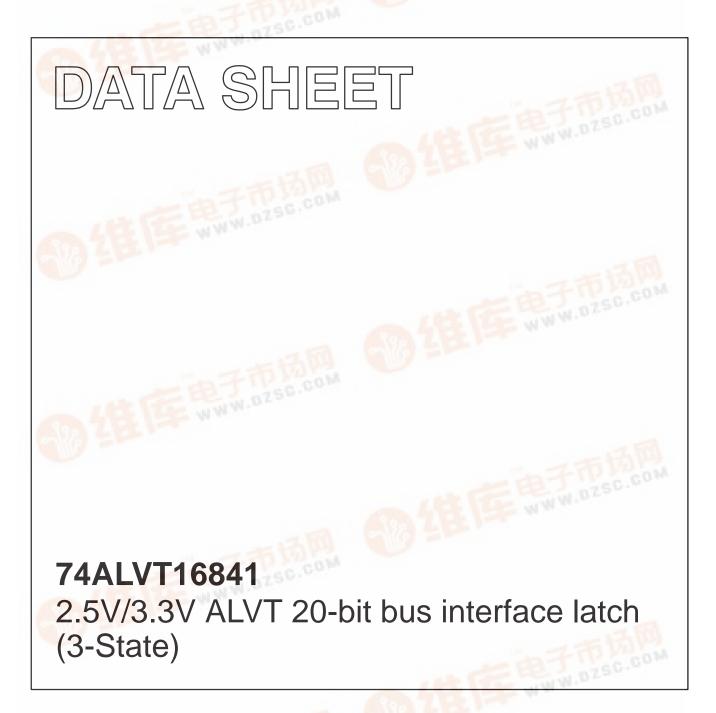
INTEGRATED CIRCUITSPOBIT样工厂,24小时加約



Product specification Supersedes data of 1996 Aug 28 IC23 Data Handbook 1998 Feb 13







74ALVT16841

FEATURES

- High speed parallel latches
- 5V I/O Compatible
- Live insertion/extraction permitted
- Extra data width for wide address/data paths or buses carrying parity
- Power-up 3-State
- Power-up reset
- Ideal where high speed, light loading, or increased fan-in are required with MOS microprocessors
- Output capability: +64mA/–32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74ALVT16841 Bus interface latch is designed to provide extra data width for wider data/address paths of buses carrying parity. It is designed for $\rm V_{CC}$ operation at 2.5V or 3.3V with I/O compatibility to 5V.

The 74ALVT16841 consists of two sets of ten D-type latches with 3-State outputs. The flip-flops appear transparent to the data when Latch Enable (nLE) is High. This allows asynchronous operation, as the output transition follows the data in transition. On the nLE High-to-Low transition, the data that meets the setup and hold time is latched.

Data appears on the bus when the Output Enable $(n\overline{OE})$ is Low. When $n\overline{OE}$ is High the output is in the High-impedance state.

QUICK REFERE	NCE DATA

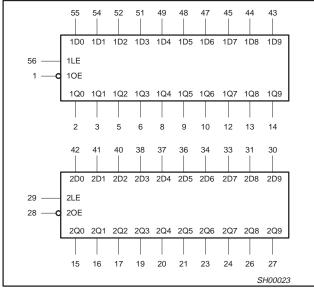
SYMBOL	PARAMETER	CONDITIONS	ТҮРІ	UNIT	
STMBOL	FARAMETER	T _{amb} = 25°C	2.5V	3.3V	UNIT
t _{PLH} t _{PHL}	Propagation delay nDx to nQx	C _L = 50pF	1.8 2.1	1.5 1.7	ns
C _{IN}	Input capacitance DIR, OE	$V_I = 0V \text{ or } V_{CC}$	3	3	pF
C _{Out}	Output pin capacitance	$V_{I/O} = 0V \text{ or } V_{CC}$	9	9	pF
I _{CCZ}	Total supply current	Outputs disabled	40	70	μA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVT16841 DL	AV16841 DL	SOT371-1
56-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVT16841 DGG	AV16841 DGG	SOT364-1

74ALVT16841

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)

		1
_1	EN2	
56	C1	
	EN4	
_29	C3	
l		
55	1D 2 V	2
54		3
52		5
51		6
49		8
48		9
_47		10
45		12
44		13
43		14
42	3D 4 V	15
41		16
40		17
38		19
37		20
36		21
34		23
33		24
31		26
30		27
		SA00077

1 0E		56 1LE
1Q0 [2	55 1D0
1Q1 [3	54 1D1
GND [4	53 GND
1Q2 [5	52 1D2
1Q3 [6	51 1D3
Vcc [7	50 VCC
1Q4 [8	49 1D4
1Q5 [9	48 1D5
1Q6 [10	47 1D6
GND [11	46 GND
1Q7 [12	45 1D7
1Q8 [13	44 1D8
1Q9 [14	43 1D9
2Q0 [15	42 2D0
2Q1 [16	41 2D1
2Q2 [17	40 2D2
GND	18	39 GND
2Q3 [19	38 2D3
2Q4	20	37 2D4
2Q5	21	36 2D5
VCC	22	35 V _{CC}
2Q6	23	34 2D6
2Q7	24	33 2D7
GND	25	32 GND
2Q8	26	31 2D8
2Q9 [27	30 2D9
2 0E	28	29 2LE
	L	
		SA00076

74ALVT16841

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
55, 54, 52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33, 31, 30	1D0 – 1D9 2D0 – 2D9	Data inputs
2, 3, 5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24, 26, 27	1Q0 – 1Q9 2Q0 – 2Q9	Data outputs
1, 28	10E, 20E	Output enable inputs (active-Low)
56, 29	1LE, 2LE	Latch enable inputs (active rising edge)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

FUNCTION TABLE

	INPUTS		OUTPUTS	OPERATING MODE		
nOE	nLE	nDx	nQ0 – nQ9	OPERATING MODE		
L	H H	L H	L H	Transparent		
L	$\rightarrow \rightarrow$	l h	L H	Latched		
н	Х	Х	Z	High impedance		
L	L	Х	NC	Hold		

H = High voltage level
h = High voltage level one set-up time prior to the High-to-Low LE transition

L =

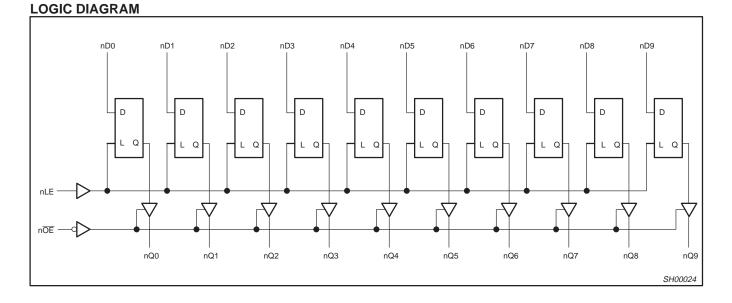
Low voltage level Low voltage level one set-up time prior to the High-to-Low LE = transition

High-to-Low LE transition =

NC= No change

J.

X = Don't care Z = High impedance "off" state



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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in Low state	128	
IOUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

2. temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		2.5V RANGE LIMITS		3.3V RANGE LIMITS	
STMBOL			MAX	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
VI	Input voltage	0	5.5	0	5.5	V
V _{IH}	High-level input voltage	1.7		2.0		V
V _{IL}	Input voltage		0.7		0.8	V
I _{OH}	High-level output current		-8		-32	mA
IOL	Low-level output current		8		32	mA
'OL	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		24		64	
$\Delta t / \Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C

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					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 3.0V; I_{IK} = -18mA$			-0.85	-1.2	V
N/		$V_{CC} = 3.0$ to 3.6V; $I_{OH} = -100\mu A$		V _{CC} -0.2	V _{CC}		v
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -32mA		2.0	2.3		v
		V _{CC} = 3.0V; I _{OL} = 100μA			0.07	0.2	
		V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 32mA			0.3	0.5	V
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
V _{RST}	Power-up output low voltage ⁶	$V_{CC} = 3.6V$; $I_O = 1mA$; $V_I = V_{CC}$ or GND				0.55	V
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$	Control pins		0.1	±1	
L 1.	Input lookage ourrept	$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$			0.1	10	
l II	Input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data pins ⁴		0.5	1	μA
		$V_{CC} = 3.6V; V_{I} = 0V$	Data pins .		0.1	-5	
I _{OFF}	Off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$	•		0.1	±100	μA
	Bus Hold current	$V_{CC} = 3V; V_I = 0.8V$		75	130		
I _{HOLD}	Data inputs ⁷	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-140		μA
	Data inputs.	$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I _{EX}	Current into an output in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			10	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} OE/OE = Don't care			1	±100	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_O = 3.0V; V_I = V_{IL} \text{ or } V_{IH}$			0.5	5	μA
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	-5	μA
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or V_{CC} , $I_O = 0$			0.07	0.1	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V _I = GND or V	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$		3.2	7	mA
Iccz	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GND$) or $V_{CC, I_{O}} = 0^5$		0.07	0.1	
ΔI _{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6° Other inputs at V_{CC} or GND	V,		0.04	0.4	mA

DC ELECTRICAL CHARACTERISTICS (3.3V ±0.3V RANGE)

NOTES:

All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
6. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

7. This is the bus hold overdrive current required to force the input to the opposite logic state.

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$\begin{array}{l} \textbf{AC CHARACTERISTICS (3.3V \pm 0.3V RANGE)} \\ \textbf{GND} = 0 \text{V}; \ \textbf{t}_{R} = \textbf{t}_{F} = 2.5 \text{ns}; \ \textbf{C}_{L} = 50 \text{pF}; \ \textbf{R}_{L} = 500 \Omega; \ \textbf{T}_{amb} = -40^{\circ} \text{C} \text{ to } +85^{\circ} \text{C}. \end{array}$

				LIMITS			
SYMBOL	PARAMETER	WAVEFORM		T _{amb} = -40 to +85°C V _{CC} = +3.3V ±0.3V			
			MIN	TYP	MAX	1	
t _{PLH} t _{PHL}	Propagation delay nDx to nQx	2	0.5 0.5	1.5 1.7	2.5 2.7	ns	
t _{PLH} t _{PHL}	Propagation delay nLE to nQx	1	1.0 1.5	2.1 3.4	3.2 5.5	ns	
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	1.0 0.5	2.3 1.3	3.6 2.3	ns	
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	4 5	1.5 1.5	3.2 2.8	4.9 4.3	ns	

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25^{\circ}C.

AC SETUP REQUIREMENTS (3.3V ±0.3V RANGE)

GND = 0V, $t_R = t_F = 2.5$ ns, $C_L = 50$ pF, $R_L = 500\Omega$

			LIN	NITS	
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = -4 V _{CC} = +3	0 to +85°C .3V ±0.3V	UNIT
			Min	Тур	
t _s (H) t _s (L)	Setup time, High or Low nDx to nLE	3	1.0 1.0	0 0	ns
t _h (H) t _h (L)	Hold time, High or Low nDx to nLE	3	1.2 1.2	0.1 0.3	ns
t _w (H)	nLE pulse width High	1	1.5		ns

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				LIMITS Temp = -40°C to +85°C			UNIT
SYMBOL PARAMETER	PARAMETER	TEST CONDITIONS					
				MIN	TYP ¹	MAX	1
VIK	Input clamp voltage	V _{CC} = 2.3V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH} High-level output voltage	$V_{CC} = 2.3$ to 3.6V; $I_{OH} = -100\mu A$		V _{CC} -0.2	V _{CC}		V	
	V _{CC} = 2.3V; I _{OH} = -8mA	V _{CC} = 2.3V; I _{OH} = -8mA		2.1		V	
		V _{CC} = 2.3V; I _{OL} = 100μA			0.07	0.2	
V _{OL} Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 24mA			0.3	0.5	V	
		V _{CC} = 2.3V; I _{OL} = 8mA				0.4	1
V _{RST}	Power-up output low voltage ⁷	$V_{CC} = 2.7V$; $I_{O} = 1mA$; $V_{I} = V_{CC}$ or GND				0.55	V
		$V_{CC} = 2.7V$; $V_I = V_{CC}$ or GND	Control pins		0.1	±1	
II Input leakage current		$V_{CC} = 0 \text{ or } 2.7 \text{V}; \text{ V}_{I} = 5.5 \text{V}$			0.1	1 10	
	input leakage current	$V_{CC} = 2.7 V; V_{I} = V_{CC}$	Data siss ⁴	Data pipa4	0.1	1	μΑ
		$V_{CC} = 2.7V; V_1 = 0$	Data pins ⁴		0.1	-5	
I _{OFF}	Off current	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$			0.1	±100	μA
I _{HOLD}	Bus Hold current	V _{CC} = 2.3V; V ₁ = 0.7V			90		
·HOLD	Data inputs ⁶	$V_{CC} = 2.3V; V_{I} = 1.7V$			-10		μA
I _{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 2.3V$			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} ; OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	$V_{CC} = 2.7V; V_{O} = 2.3V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	5	μA
I _{OZL}	3-State output Low current	V_{CC} = 2.7V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}			0.5	-5	μΑ
I _{CCH}		V_{CC} = 2.7V; Outputs High, V_{I} = GND or V	V _{CC} , I _{O =} 0		0.04	0.1	
I _{CCL}	Quiescent supply current	V_{CC} = 2.7V; Outputs Low, V_{I} = GND or V_{CC} , I_{O} = 0			2.3	4.5	mA
I _{CCZ}		V_{CC} = 2.7V; Outputs Disabled; V_{I} = GND or $V_{CC,\ I_{O}}$ = 0^{5}			0.04	0.1]
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 2.3V to 2.7V; One input at V_{CC} -0. Other inputs at V_{CC} or GND		0.04	0.4	mA	

DC ELECTRICAL CHARACTERISTICS (2.5V ± 0.2V RANGE)

NOTES:

All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V ± 0.2V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground. 6. Not guaranteed.

7. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

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$\begin{array}{l} \textbf{AC CHARACTERISTICS (2.5V \pm 0.2V RANGE)} \\ \textbf{GND} = 0 \text{V}; \ \textbf{t}_{R} = \textbf{t}_{F} = 2.5 \text{ns}; \ \textbf{C}_{L} = 50 \text{pF}; \ \textbf{R}_{L} = 500 \Omega; \ \textbf{T}_{amb} = -40^{\circ} \text{C} \text{ to } +85^{\circ} \text{C}. \end{array}$

				LIMITS			
SYMBOL	PARAMETER	WAVEFORM	T _{ar} V	_{mb} = -40 to +85 _{CC} = +2.5V ±0.	5°C 2V	UNIT	
			MIN	TYP	MAX		
t _{PLH} t _{PHL}	Propagation delay nDx to nQx	2	0.5 0.5	1.8 2.1	3.0 3.6	ns	
t _{PLH} t _{PHL}	Propagation delay nLE to nQx	1	1.0 2.0	2.7 4.2	4.3 6.5	ns	
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	1.5 0.5	3.0 1.8	4.0 3.2	ns	
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	4 5	1.5 1.0	3.1 2.4	4.5 3.8	ns	

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC SETUP REQUIREMENTS (2.5V ±0.2V RANGE)

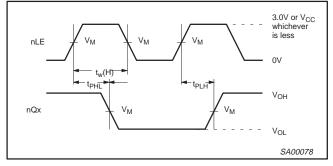
GND = 0V, t_{R} = t_{F} = 2.5ns, C_{L} = 50pF, R_{L} = 500 Ω

			LIN	NITS		
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = -4 V _{CC} = +2	0 to +85°C 2.5V ±0.2V	UNIT	
			Min	Тур		
t _s (H) t _s (L)	Setup time, High or Low nDx to nLE	3	0.5 1.5	0 0.2	ns	
t _h (H) t _h (L)	Hold time, High or Low nDx to nLE	3	1.8 2.0	0 0.8	ns	
t _w (H)	nLE pulse width High	1	1.5		ns	

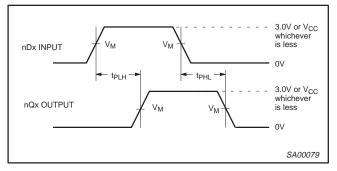
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AC WAVEFORMS

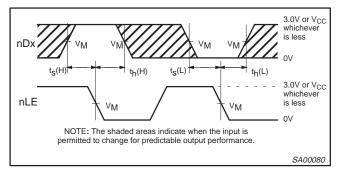
 $\begin{array}{l} \mathsf{V}_{\mathsf{M}} = 1.5\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{M}} = \mathsf{V}_{\mathsf{CC}}/2 \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \mathsf{V}_{\mathsf{X}} = \mathsf{V}_{\mathsf{OL}} + 0.3\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{X}} = \mathsf{V}_{\mathsf{OL}} + 0.15\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \mathsf{V}_{\mathsf{Y}} = \mathsf{V}_{\mathsf{OH}} - 0.3\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \geq 3.0\mathsf{V}; \ \mathsf{V}_{\mathsf{Y}} = \mathsf{V}_{\mathsf{OH}} - 0.15\mathsf{V} \text{ at } \mathsf{V}_{\mathsf{CC}} \leq 2.7\mathsf{V} \\ \end{array}$



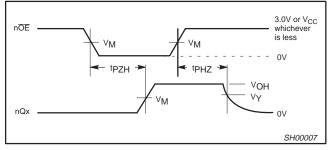
Waveform 1. Propagation Delay, Latch Enable Input to Output, and Enable Pulse Width



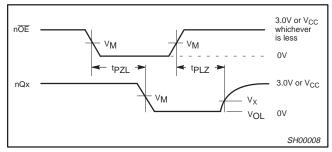
Waveform 2. Propagation Delay for Data to Outputs



Waveform 3. Data Setup and Hold Times



Waveform 4. 3-State Output Enable Time to High Level and Output Disable Time from High Level



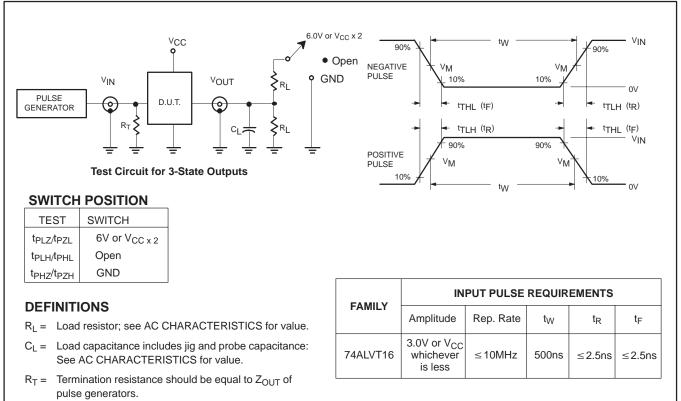
Waveform 5. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

SW00025

2.5V/3.3V 20-bit bus interface latch (3-State)

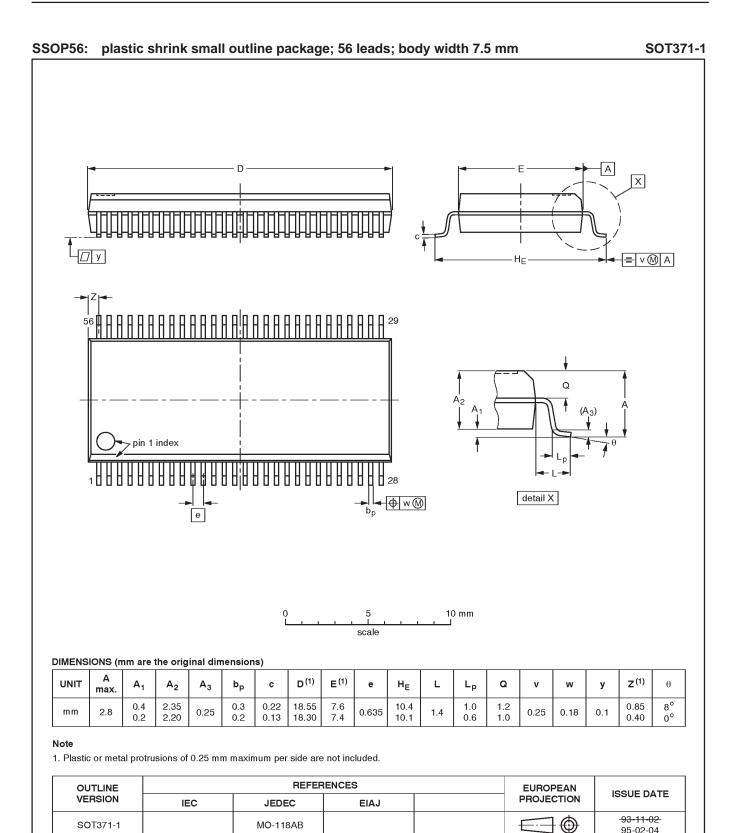
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TEST CIRCUIT AND WAVEFORM



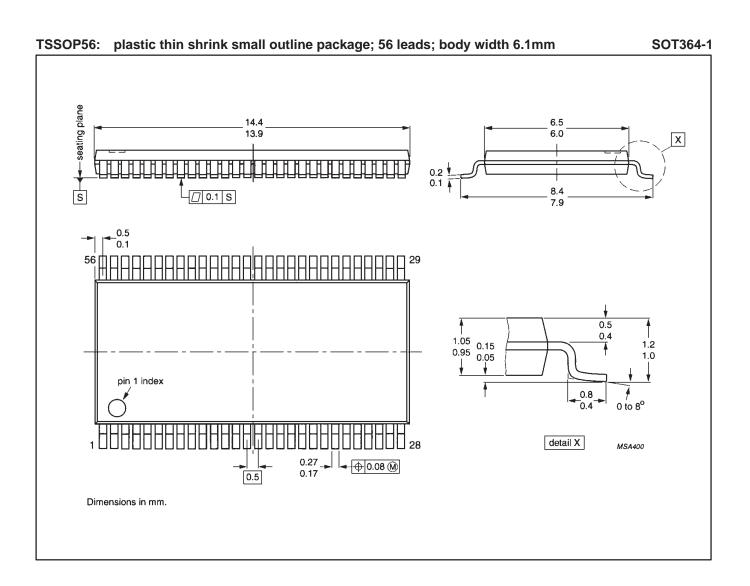
95-02-04

2.5V/3.3V ALVT 20-bit bus interface latch (3-State)



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Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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